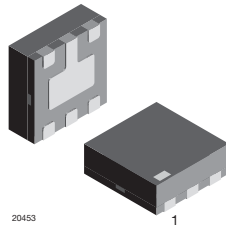
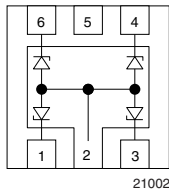
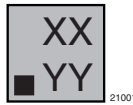


## 4-Line (Quad) ESD Protection Diode Array in LLP75-6L



### MARKING (example only)



Dot = pin 1 marking  
 XX = date code  
 YY = type code (see table below)

### DESIGN SUPPORT TOOLS

[click logo to get started](#)



### FEATURES

- Compact LLP75-6L package
- Low package height < 0.6 mm
- 4-line ESD protection (quad)
- Low leakage current < 0.1  $\mu$ A
- Low load capacitance  $C_D = 6$  pF
- ESD immunity acc. IEC 61000-4-2  
 $\pm 8$  kV contact discharge  
 $\pm 10$  kV air discharge
- Surge current acc. IEC 61000-4-5  $I_{PP} > 1.5$  A
- Soldering can be checked by standard vision inspection. No X-ray necessary
- e4 - precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



ORDERING INFORMATION			
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY
VESD09A4A-HSF	VESD09A4A-HSF-GS08	3000	15 000

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD09A4A-HSF	LLP75-6L	49	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

ABSOLUTE MAXIMUM RATINGS VESD09A4A-HSF				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	BiAs-mode: each input (pin 1, 3 - 5) to ground (pin 2 and 6); acc. IEC 61000-4-5; $t_p = 8/20$ $\mu$ s; single shot	$I_{PPM}$	1.5	A
Peak pulse power	BiAs-mode: each input (pin 1, 3 - 5) to ground (pin 2 and 6); acc. IEC 61000-4-5; $t_p = 8/20$ $\mu$ s; single shot	$P_{PP}$	30	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses BiAs-mode: each input (pin 1, 3 - 5) to ground (pin 2 and 6)	$V_{ESD}$	$\pm 8$	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses BiAs-mode: each input (pin 1, 3 - 5) to ground (pin 2 and 6)	$V_{ESD}$	$\pm 10$	kV
Operating temperature	Junction temperature	$T_J$	-40 to +125	°C
Storage temperature		$T_{STG}$	-55 to +150	°C

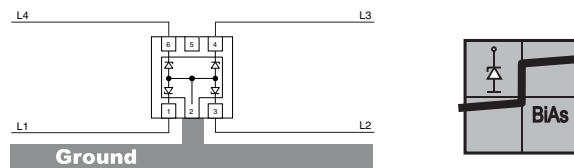
## BiAs-MODE (4-line bidirectional asymmetrical protection mode)

With the VESD09A4A-HSF up to 4 signal- or data-lines (L1 to L4) can be protected against voltage transients. With pin 2 connected to ground and pin 1, 3, 4 and 6 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage ( $V_{RWM}$ ) the protection diode between data line and ground offer a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage ( $V_C$ ) is defined by the breakthrough voltage ( $V_{BR}$ ) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage ( $V_F$ ) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD09A4A-HSF clamping behaviour is bidirectional and asymmetrical (BiAs).



21003

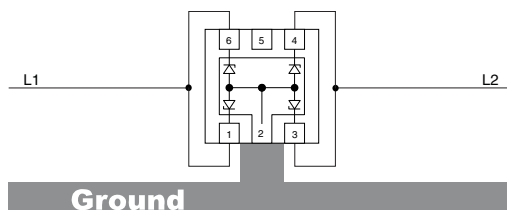
<b>ELECTRICAL CHARACTERISTICS VESD09A4A-HSF (Pin 1, 3, 4, or 5 to pin 2)</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	$N_{channel}$	-	-	1	lines
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	9	V
Reverse voltage	at $I_R = 0.1\text{ }\mu\text{A}$	$V_R$	9	-	-	V
Reverse current	at $V_R = V_{RWM} = 9\text{ V}$	$I_R$	-	< 0.01	0.1	$\mu\text{A}$
Reverse breakdown voltage	at $I_R = 1\text{ mA}$	$V_{BR}$	11.2	-	13	V
Reverse clamping voltage	at $I_{PP} = 1.5\text{ A}$ , acc. IEC 61000-4-5	$V_C$	-	-	23	V
Forward clamping voltage	at $I_F = 1.5\text{ A}$ , acc. IEC 61000-4-5	$V_F$	-	-	2	V
Capacitance	at $V_R = 0\text{ V}$ ; $f = 1\text{ MHz}$	$C_D$	-	6.2	10	pF
	at $V_R = 4.5\text{ V}$ ; $f = 1\text{ MHz}$	$C_D$	-	3.2	4	pF

### Note

- BiAs mode (between pin 1 and pin 2).

If a higher surge current or peak pulse current ( $I_{PP}$ ) is needed, some protection diodes in the VESD09A4A-HSF can also be used in parallel in order to "multiply" the performance. If two diodes are switched in parallel you get

- double surge power = double peak pulse current ( $2 \times I_{PPM}$ )
- half of the line inductance = reduced clamping voltage
- half of the line resistance = reduced clamping voltage
- double line capacitance ( $2 \times C_D$ )
- double reverse leakage current ( $2 \times I_R$ )



21004

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

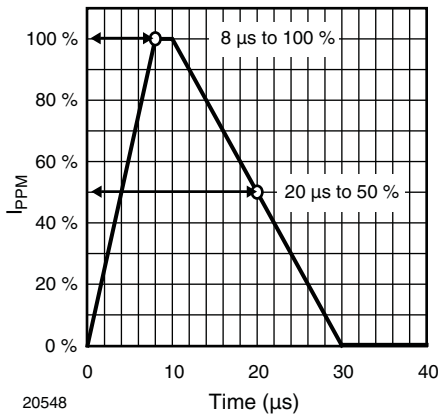


Fig. 1 - ESD Discharge Current Wave Form  
acc. IEC 61000-4-2 (330  $\Omega$ /150 pF)

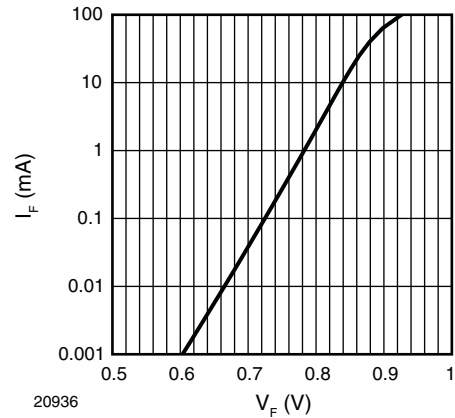


Fig. 4 - Typical Forward Current  $I_F$  vs. Forward Voltage  $V_F$

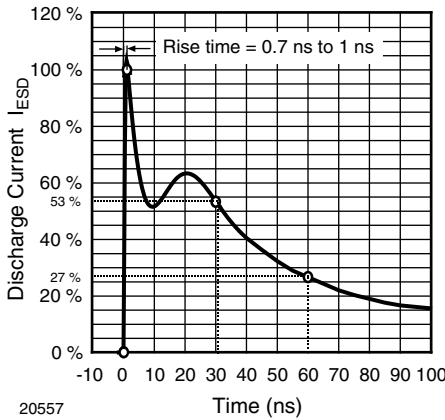


Fig. 2 - 8/20  $\mu\text{s}$  Peak Pulse Current Wave Form  
acc. IEC 61000-4-5

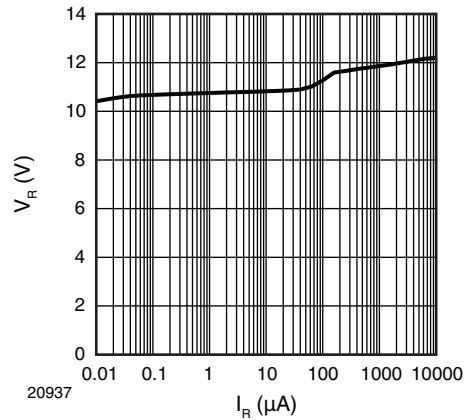


Fig. 5 - Typical Reverse Voltage  $V_R$  vs. Reverse Current  $I_R$

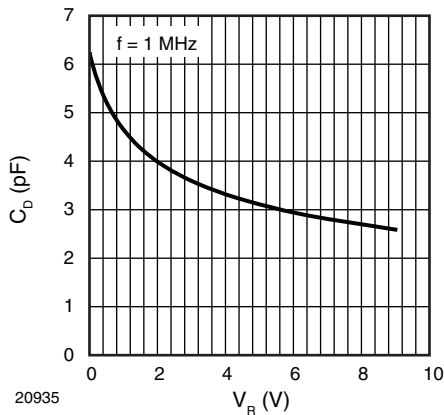


Fig. 3 - Typical Capacitance  $C_D$  vs. Reverse Voltage  $V_R$

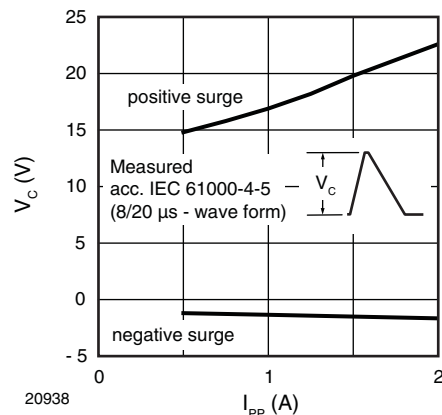


Fig. 6 - Typical Peak Clamping Voltage  $V_C$  vs. Peak Pulse Current  $I_{PP}$

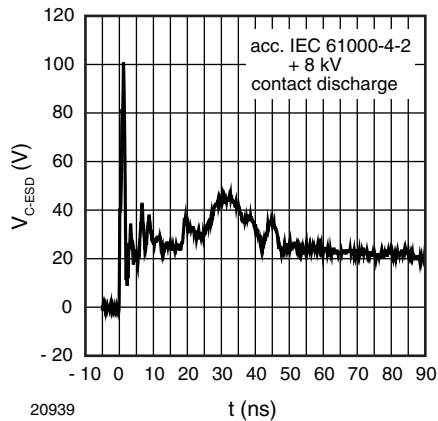


Fig. 7 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

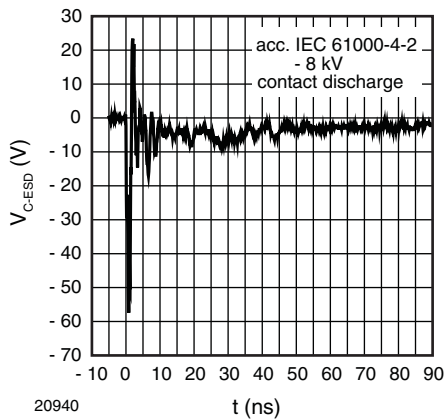


Fig. 8 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

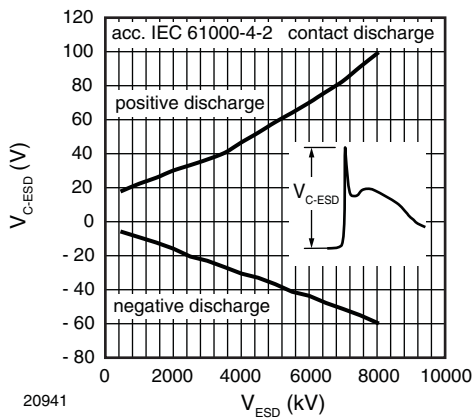
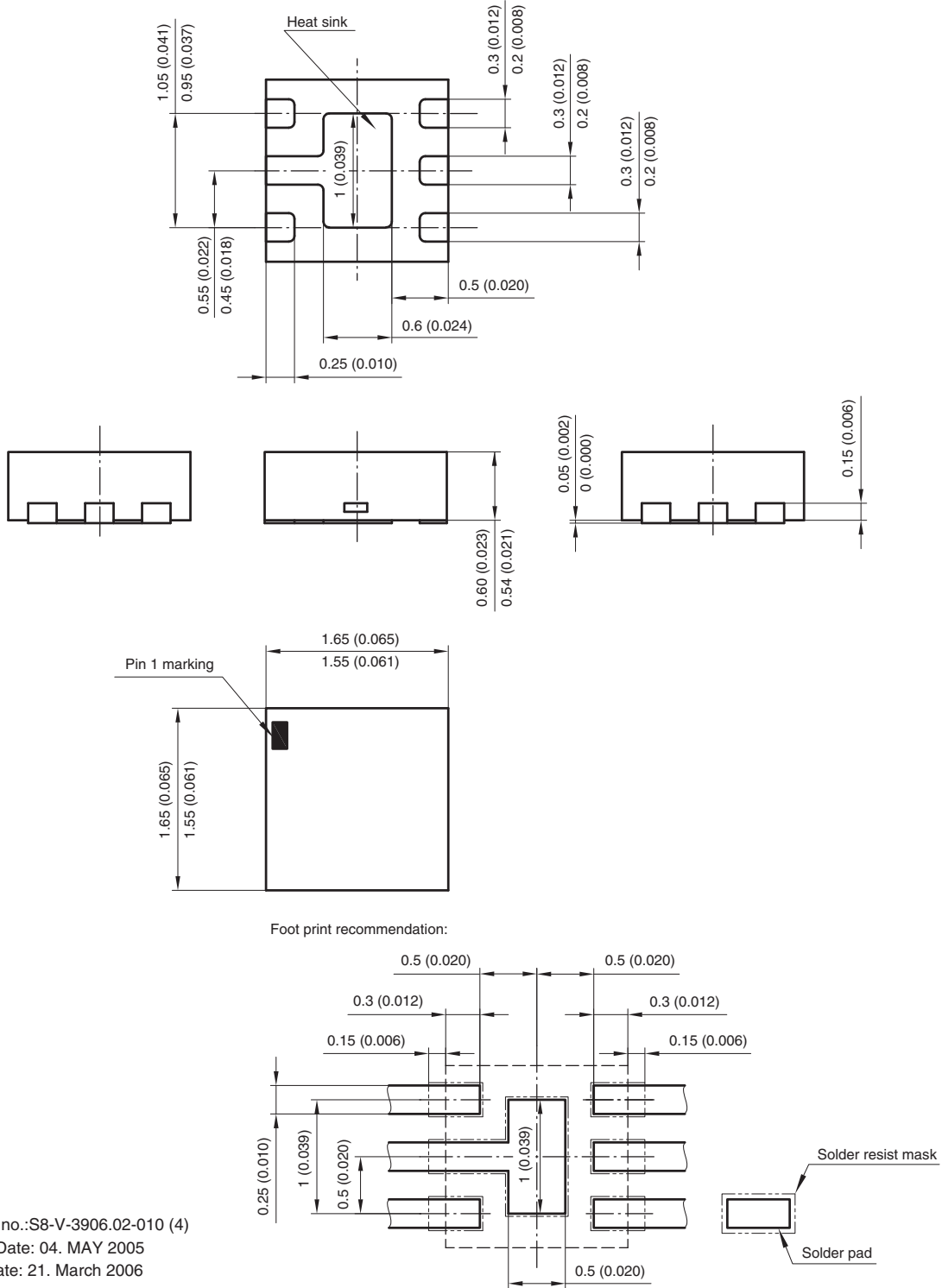


Fig. 9 - Typical Peak Clamping Voltage at ± ESD Contact Discharge (acc. IEC 61000-4-2)

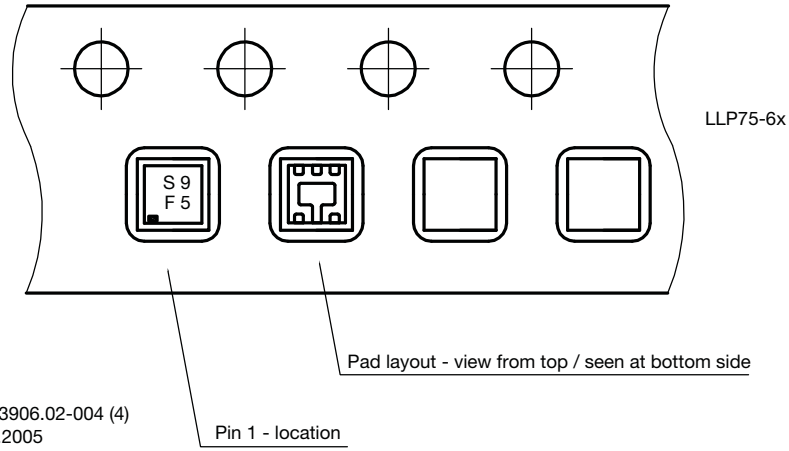


**PACKAGE DIMENSIONS** in millimeters (Inches): **LLP75-6L**



Foot print recommendation:

Document no.:S8-V-3906.02-010 (4)  
Created - Date: 04. MAY 2005  
Rev. 4 - Date: 21. March 2006  
20454



S8-V-3906.02-004 (4)  
10.01.2005



## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.